NSN 5961-01-038-2057 Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.140 inches and 0.155 inches	
Overall Diameter:	
Between 0.060 inches and 0.075 inches	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
1.2 forward voltage, average	
Current Rating Per Characteristic:	
-4.00 amperes source cutoff current preset	
Power Rating Per Characteristic:	
-500.0 milliwatts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Test Data Document:	
00724-20-00760 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer dra	awing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
	
Demilitarization:	
No	
Fiig:	
A110a0	